











OPA2172-Q1, OPA4172-Q1

SBOS809A - NOVEMBER 2016-REVISED JUNE 2017

# OPAx172-Q1 36-V, Single-Supply, 10-MHz, Rail-to-Rail Output Automotive Grade **Operational Amplifiers**

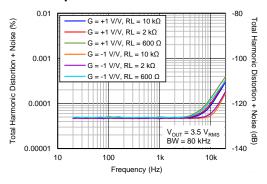
#### **Features**

- Qualified for Automotive Applications
- AEC-Q100 Qualified With the Following Results:
  - Device Temperature Grade 1: -40°C to +125°C Ambient Operating Temperature Range
  - Device HBM ESD Classification Level 3A
  - Device CDM ESD Classification level C6
- Wide Supply Range: 4.5 V to 36 V, ±2.25 V to ±18 V
- Low Offset Voltage: ±0.2 mV
- Low Offset Drift: ±0.3 µV/°C
- Gain Bandwidth: 10 MHz
- Low Input Bias Current: ±8 pA
- Low Quiescent Current: 1.6 mA per Amplifier
- Low Noise: 7 nV/√Hz
- EMI and RFI Filtered Inputs
- Input Range Includes the Negative Supply
- Input Range Operates to Positive Supply
- Rail-to-Rail Output
- High Common-Mode Rejection: 120 dB
- Industry-Standard Packages:
  - VSSOP-8, TSSOP-14

# **Applications**

- Automotive
- **HEV and EV Power Trains**
- Advanced Driver Assist (ADAS)
- **Automatic Climate Controls**
- Avionics, Landing Gear
- Medical Instrumentation
- Current Sense

#### Superior THD Performance



# 3 Description

The OPA2172-Q1 and OPA4172-Q1 (OPAx172-Q1) are a family of 36-V, single-supply, low-noise operational amplifiers capable of operating on supplies ranging from 4.5 V (±2.25 V) to 36 V (±18 V). The OPAx172-Q1 are available in micropackages, and offer low offset, drift, and quiescent current. These devices also offer wide bandwidth, fast slew rate, and high output current drive capability. The dual and quad versions all have identical specifications for maximum design flexibility.

Unlike most op amps that are specified at only one supply voltage, the OPAx172-Q1 family is specified from 4.5 V to 36 V. Input signals beyond the supply rails do not cause phase reversal. The input can operate 100 mV below the negative rail and within 2 V of the top rail during normal operation. Note that these devices can operate with full rail-to-rail input 100 mV beyond the top rail, but with reduced performance within 2 V of the top rail.

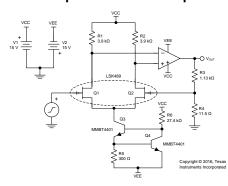
The OPAx172-Q1 series of op amps are specified from -40°C to +125°C.

#### Device Information<sup>(1)</sup>

| PART NUMBER | PACKAGE    | BODY SIZE (NOM)   |  |  |  |  |  |  |
|-------------|------------|-------------------|--|--|--|--|--|--|
| OPA2172-Q1  | VSSOP (8)  | 3.00 mm × 3.00 mm |  |  |  |  |  |  |
| OPA4172-Q1  | TSSOP (14) | 5.00 mm × 4.40 mm |  |  |  |  |  |  |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

#### JFET-Input Low-Noise Amplifier





# **Table of Contents**

| 1 Fe            | atures 1                        | 9  | Applications and Implementation                      | . 20 |
|-----------------|---------------------------------|----|--|------|
| 2 Ap            | plications 1                    |    | 9.1 Application Information                          | . 20 |
| 3 De            | escription 1                    |    | 9.2 Typical Applications                             | . 20 |
|                 | evision History 2               | 10 | Power Supply Recommendations                         | . 24 |
|                 | evice Comparison Table          | 11 | Layout   | 24   |
|                 | n Configuration and Functions 3 |    | 11.1 Layout Guidelines                               | . 24 |
|                 | pecifications4                  |    | 11.2 Layout Example                                  | . 25 |
| •               | 1 Absolute Maximum Ratings 4    | 12 | Device and Documentation Support                     | . 26 |
| 7.2             | <u> </u>                        |    | 12.1 Device Support                                  | . 26 |
| 7.3             | 5                               |    | 12.2 Documentation Support                           | . 26 |
| 7.4             |                                 |    | 12.3 Related Links                                   | . 26 |
| 7.5             |                                 |    | 12.4 Receiving Notification of Documentation Updates | s 26 |
| 7.6             |                                 |    | 12.5 Community Resources                             | . 27 |
|                 | stailed Description14           |    | 12.6 Trademarks                                      | . 27 |
| 8. <sup>-</sup> |                                 |    | 12.7 Electrostatic Discharge Caution                 | . 27 |
| 8.2             |                                 |    | 12.8 Glossary  | . 27 |
| 8.3             | <u> </u>                        | 13 | Mechanical, Packaging, and Orderable                 | 0-   |
| 8.4             | 4 Device Functional Modes 17    |    | Information  | 21   |

# 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| CI | hanges from Original (November 2016) to Revision A  | Page |
|----|---|------|
| •  | Deleted OPA172-Q1 throughout data sheet   | 1    |
| •  | Deleted Operating temperature, T <sub>A</sub> from Absolute Maximum Ratings   | 4    |
| •  | Added OPA4172-Q1 in PW package to ESD Ratings table   | 4    |
| •  | Changed values in the <i>Thermal Information</i> table to align with JEDEC standards.   | 4    |
| •  | Deleted value: $\pm 14$ and temperature range: $T_A = -40^{\circ}\text{C}$ to $\pm 125^{\circ}\text{C}$ from Input bias current and added $T_A = 25^{\circ}\text{C}$ to Input bias current and Input offset current | 5    |
| •  | Changed TYP value from: 2.5 to: 2 for Input voltage noise, E <sub>n</sub>   | 5    |
| •  | Deleted Specified temperature from <i>Electrical Characteristics</i> table  | 6    |
| •  | Changed figure: Operational Amplifier Board Layout for a Noninverting Configuration with revised content  | 25   |

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# 5 Device Comparison Table

#### **Table 1. Device Comparison**

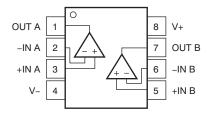
| DEVICE            | PACKAGE  |
|-------------------|----------|
| OPA2172-Q1 (dual) | VSSOP-8  |
| OPA4172-Q1 (quad) | TSSOP-14 |

# **Table 2. Device Family Comparison**

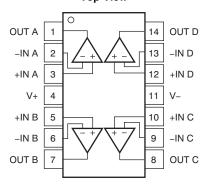
| DEVICE  | QUIESCENT CURRENT (I <sub>Q</sub> ) | GAIN BANDWIDTH PRODUCT (GBP) | VOLTAGE NOISE DENSITY (e <sub>n</sub> ) |
|---------|-------------------------------------|------------------------------|---|
| OPAx172 | 1600 μΑ                             | 10 MHz                       | 7 nV/√ <del>Hz</del>                    |
| OPAx171 | 475 μA                              | 3.0 MHz                      | 14 nV/√Hz                               |
| OPAx170 | 110 μΑ                              | 1.2 MHz                      | 19 nV/√Hz                               |

# 6 Pin Configuration and Functions





#### OPA4172-Q1 PW Package 14-Pin TSSOP Top View



#### **Pin Functions**

|       | PIN         |            |          |                                 |
|-------|-------------|------------|----------|---------------------------------|
| NAME  | OPA2172-Q1  | OPA4172-Q1 | I/O      |                                 |
| NAME  | DGK (VSSOP) | PW (TSSOP) |          | DESCRIPTION                     |
| –IN A | 2           | 2          | Ι        | Inverting input, channel A      |
| –IN B | 6           | 6          | Ι        | Inverting input, channel B      |
| –IN C | _           | 9          | Ι        | Inverting input,,channel C      |
| –IN D | _           | 13         | Ι        | Inverting input, channel D      |
| +IN A | 3           | 3          | Ι        | Noninverting input, channel A   |
| +IN B | 5           | 5          | Ι        | Noninverting input, channel B   |
| +IN C | _           | 10         | Ι        | Noninverting input, channel C   |
| +IN D | _           | 12         | Ι        | Noninverting input, channel D   |
| OUT A | 1           | 1          | 0        | Output, channel A               |
| OUT B | 7           | 7          | 0        | Output, channel B               |
| OUT C | _           | 8          | 0        | Output, channel C               |
| OUT D | _           | 14         | 0        | Output, channel D               |
| V-    | 4           | 11         |          | Negative (lowest) power supply  |
| V+    | 8           | 4          | <u> </u> | Positive (highest) power supply |

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Product Folder Links: OPA2172-Q1 OPA4172-Q1



# 7 Specifications

#### 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

|                         |   |             | MIN        | MAX        | UNIT |
|-------------------------|---|-------------|------------|------------|------|
|                         | Supply voltage, V+ to V-                        |             | -20        | 20         |      |
| Voltage                 | Single-supply voltage                           |             |            | 40         | V    |
|                         | Signal input ping valtage (2)                   | Common-mode | (V-) - 0.5 | (V+) + 0.5 | V    |
|                         | Signal input pins voltage (2)  Differential (3) |             | -0.5       | 0.5        |      |
| Command                 | Signal input pins current                       |             | -10        | 10         | mA   |
| Current                 | Output short-circuit (4)                        |             | Conti      | nuous      |      |
| Tomporotura             | Junction, T <sub>J</sub>                        |             |            | 150        | °C   |
| Sig Sig Out Temperature | Storage, T <sub>stg</sub>                       |             | -65        | 150        |      |

<sup>(1)</sup> Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

# 7.2 ESD Ratings

|                    |   |   | VALUE | UNIT |  |
|--------------------|---|---|-------|------|--|
| OPA217             | 72-Q1 in DGK package  |   |       |      |  |
| V                  | Human-body model (HBM), per AEC Q100-002 <sup>(1)</sup>                                 |   | ±4000 | \/   |  |
| V(ESD)             | V <sub>(ESD)</sub> Electrostatic discharge Charged-device model (CDM), per AEC Q100-011 |   | ±1000 | V    |  |
| OPA417             | OPA4172-Q1 in PW package  |   |       |      |  |
| V                  | Clastrostatia diasharas   | Human-body model (HBM), per AEC Q100-002 <sup>(1)</sup> | ±4000 | \/   |  |
| V <sub>(ESD)</sub> | Electrostatic discharge   | Charged-device model (CDM), per AEC Q100-011            | ±750  | V    |  |

<sup>(1)</sup> AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

# 7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|                             |               | MIN   | MAX | UNIT |
|-----------------------------|---------------|-------|-----|------|
| Supply voltage (//) (//)    | Single-supply | 4.5   | 36  |      |
| Supply voltage, (V+) – (V–) | Dual-supply   | ±2.25 | ±18 | V    |
| Specified temperature       |               | -40   | 125 | °C   |

#### 7.4 Thermal Information

|                        |  | OPA2172-Q1  | OPA4172-Q1 |      |
|------------------------|--|-------------|------------|------|
|                        | THERMAL METRIC <sup>(1)</sup>                | DGK (VSSOP) | PW (TSSOP) | UNIT |
|                        |  | 8 PINS      | 14 PINS    |      |
| $R_{\theta JA}$        | Junction-to-ambient thermal resistance       | 181.4       | 107.5      | °C/W |
| $R_{\theta JC(top)}$   | Junction-to-case (top) thermal resistance    | 69.2        | 32.5       | °C/W |
| $R_{\theta JB}$        | Junction-to-board thermal resistance         | 103.3       | 50.4       | °C/W |
| ΨЈТ                    | Junction-to-top characterization parameter   | 10.9        | 1.8        | °C/W |
| ΨЈВ                    | Junction-to-board characterization parameter | 101.6       | 49.6       | °C/W |
| R <sub>0</sub> JC(bot) | Junction-to-case (bottom) thermal resistance | N/A         | N/A        | °C/W |

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

<sup>(2)</sup> Transient conditions that exceed these voltage ratings must be current limited to 10 mA or less.

<sup>(3)</sup> Refer to the *Electrical Overstress* section for more information.

<sup>(4)</sup> Short-circuit to ground, one amplifier per package.



# 7.5 Electrical Characteristics

at  $T_A = 25^{\circ}C$ ,  $V_S = \pm 2.25$  V to  $\pm 18$  V,  $V_{CM} = V_{OUT} = V_S$  / 2, and  $R_L = 10$  k $\Omega$  connected to  $V_S$  / 2 (unless otherwise noted)

|                      | PARAMETER                          | TEST CONDIT  | IONS               | MIN          | TYP      | MAX        | UNIT                 |  |
|----------------------|------------------------------------|--|--------------------|--------------|----------|------------|----------------------|--|
| OFFSET V             | OLTAGE                             |  |                    |              |          |            |                      |  |
| .,                   |                                    |  |                    |              | ±0.2     | ±1         |                      |  |
| V <sub>OS</sub>      | Input offset voltage               | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$   |                    |              |          | ±1.15      | mV                   |  |
| n., ,,=              |                                    | T 1000 : 1000  | OPA4172-Q1         |              | ±0.3     | ±1.5       | 1400                 |  |
| dV <sub>OS</sub> /dT | Input offset voltage drift         | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$   | OPA2172-Q1         |              |          | ±1.8       | μV/°C                |  |
| PSRR                 | Power-supply rejection ratio       | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$   | •                  |              | ±1       | ±3         | μV/V                 |  |
|                      | Channel separation, dc             | At dc  |                    |              | 5        |            | μV/V                 |  |
| INPUT BIA            | AS CURRENT                         |  |                    |              |          |            |                      |  |
|                      |                                    | T <sub>A</sub> = 25°C  |                    |              | ±8       | ±15        | pA                   |  |
| I <sub>B</sub>       | Input bias current                 | T 40°C to .425°C   | OPA2172-Q1IDGK     |              |          | .10        | <b>~</b> Λ           |  |
|                      |                                    | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$   | OPA4172-Q11PW      |              |          | ±18        | nA                   |  |
|                      |                                    | T <sub>A</sub> = 25°C  | •                  |              | ±2       | ±15        | pA                   |  |
| Ios                  | Input offset current               | T 4000 to 140500   | OPA4172-Q1         |              |          | ±1         | ^                    |  |
|                      |                                    | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$   | OPA2172-Q1         |              |          | ±3         | nA                   |  |
| NOISE                |                                    |  |                    |              |          |            |                      |  |
| En                   | Input voltage noise                | f = 0.1 Hz to 10 Hz  |                    |              | 2        |            | $\mu V_{PP}$         |  |
|                      | Innut valtage paige density        | f = 100 Hz   |                    |              | 12       |            | m\//a/ <del>U=</del> |  |
| e <sub>n</sub>       | Input voltage noise density        | f = 1 kHz  |                    |              | 7        |            | nV/√Hz               |  |
| i <sub>n</sub>       | Input current noise density        | f = 1 kHz  |                    |              | 1.6      |            | fA/√Hz               |  |
| INPUT VO             | LTAGE                              |  |                    |              |          |            |                      |  |
| $V_{CM}$             | Common-mode voltage <sup>(1)</sup> |  |                    | (V-) - 0.1 V |          | (V+) - 2 V | V                    |  |
| CMRR                 | Common made rejection ratio        | $V_S = \pm 2.25 \text{ V}, (V-) - 0.1 \text{ V} < V_{CM} < T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}$                         | (V+) – 2 V,        | 90           | 104      |            | dB                   |  |
| CIVIKK               | Common-mode rejection ratio        | $V_S = \pm 18 \text{ V}, (V-) - 0.1 \text{ V} < V_{CM} < (V-) - 125^{\circ}\text{C}$   | (+) – 2 V,         | 110          | 120      |            | ив                   |  |
| INPUT IME            | PEDANCE                            |  |                    | ·            |          |            |                      |  |
|                      | Differential                       |  |                    |              | 100    4 |            | $MΩ \parallel pF$    |  |
|                      | Common-mode                        |  |                    |              | 6    4   |            | $10^{13}\Omega  $ pF |  |
| OPEN-LO              | OP GAIN                            |  |                    |              |          |            |                      |  |
| -                    |                                    | $(V-) + 0.35 V < V_O < (V+) - 0.35 V$  | OPA4172-Q1         | 110          | 130      |            | -                    |  |
| ^                    | Onen leen veltege gein             | $ \begin{array}{l} (V-) + 0.35 \ V < V_O < (V+) - 0.35 \ V, \\ R_L = 10 \ k\Omega, \ T_A = -40 ^{\circ} C \ to \ +125 ^{\circ} C \end{array} $ | OPA2172-Q1         | 107          | 115      |            |                      |  |
| A <sub>OL</sub>      | Open-loop voltage gain             | $(V-) + 0.5 V < V_O < (V+) - 0.5 V,$   | OPA4172-Q1         |              | 116      |            | dB                   |  |
|                      |                                    | $(V-) + 0.5 V < V_O < (V+) - 0.5 V,$<br>$R_L = 2 k\Omega, T_A = -40^{\circ}C to +125^{\circ}C$   | OPA2172-Q1         |              | 107      |            |                      |  |
| FREQUEN              | ICY RESPONSE                       |  |                    |              |          |            |                      |  |
| GBP                  | Gain bandwidth product             |  |                    |              | 10       |            | MHz                  |  |
| SR                   | Slew rate                          | G = 1  |                    |              | 10       |            | V/µs                 |  |
| +-                   | Settling time                      | To 0.1%, $V_S = \pm 18 \text{ V}$ , $G = 1$ , 10-V s   | tep                |              | 2        |            | lie.                 |  |
| t <sub>S</sub>       | Setting time                       | To 0.01% (12 bit), V <sub>S</sub> = ±18 V, G = 1, 10-V step  |                    |              | 3.2      |            | μs                   |  |
|                      | Overload recovery time             | V <sub>IN</sub> × Gain > V <sub>S</sub>  |                    |              | 200      |            | ns                   |  |
| THD+N                | Total harmonic distortion + noise  | V <sub>S</sub> = 36 V, G = 1, f = 1 kHz, V <sub>O</sub> = 3.   | 5 V <sub>RMS</sub> | (            | 0.00005% |            |                      |  |

<sup>(1)</sup> The input range can be extended beyond (V+) – 2 V up to (V+) + 0.1 V. See the *Typical Characteristics* and *Application Information* sections for additional information.



# **Electrical Characteristics (continued)**

at  $T_A$  = 25°C,  $V_S$  = ±2.25 V to ±18 V,  $V_{CM}$  =  $V_{OUT}$  =  $V_S$  / 2, and  $R_L$  = 10 k $\Omega$  connected to  $V_S$  / 2 (unless otherwise noted)

|                   | PARAMETER                          | TEST CO   | ONDITIONS                  | MIN          | TYP          | MAX      | UNIT |
|-------------------|------------------------------------|---|----------------------------|--------------|--------------|----------|------|
| OUTPU             | Т                                  |   |                            |              |              | ·        |      |
|                   |                                    | V <sub>S</sub> = +36 V  | $R_L = 10 \text{ k}\Omega$ |              | 70           | 90       |      |
|                   |                                    |   | $R_L = 2 k\Omega$          |              | 330          | 400      |      |
|                   |                                    | V <sub>S</sub> = +36 V,   | $R_L = 10 \text{ k}\Omega$ |              | 95           | 120      |      |
| Vo                | Valta an autout autie a feara sail | $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$            | $R_L = 2 k\Omega$          |              | 470          | 530      | \/   |
|                   | Voltage output swing from rail     | V <sub>S</sub> = 4.5 V  | $R_L = 10 \text{ k}\Omega$ |              | 10           | 20       | mV   |
|                   |                                    |   | $R_L = 2 k\Omega$          |              | 40           | 50       |      |
|                   |                                    | V <sub>S</sub> = 4.5 V,<br>T <sub>A</sub> = -40°C to +125°C     | $R_L = 10 \text{ k}\Omega$ |              | 10           | 25       |      |
|                   |                                    |   | $R_L = 2 k\Omega$          |              | 55           | 70       |      |
| I <sub>SC</sub>   | Short-circuit current              |   |                            |              | ±75          |          | mA   |
| C <sub>LOAD</sub> | Capacitive load drive              |   |                            | See the Typi | cal Characte | eristics | pF   |
| Z <sub>O</sub>    | Open-loop output impedance         | f = 1 MHz, I <sub>O</sub> = 0 A                                 |                            |              | 60           |          | Ω    |
| POWER             | SUPPLY                             |   |                            | ·            |              |          |      |
| Vs                | Specified voltage                  |   |                            | 4.5          |              | 36       | V    |
|                   | Quiescent current per              | I <sub>O</sub> = 0 A  |                            |              | 1.6          | 1.8      | A    |
| IQ                | amplifier                          | $I_O = 0 \text{ A}, T_A = -40^{\circ}\text{C to } +125^{\circ}$ | rC                         |              |              | 2        | mA   |

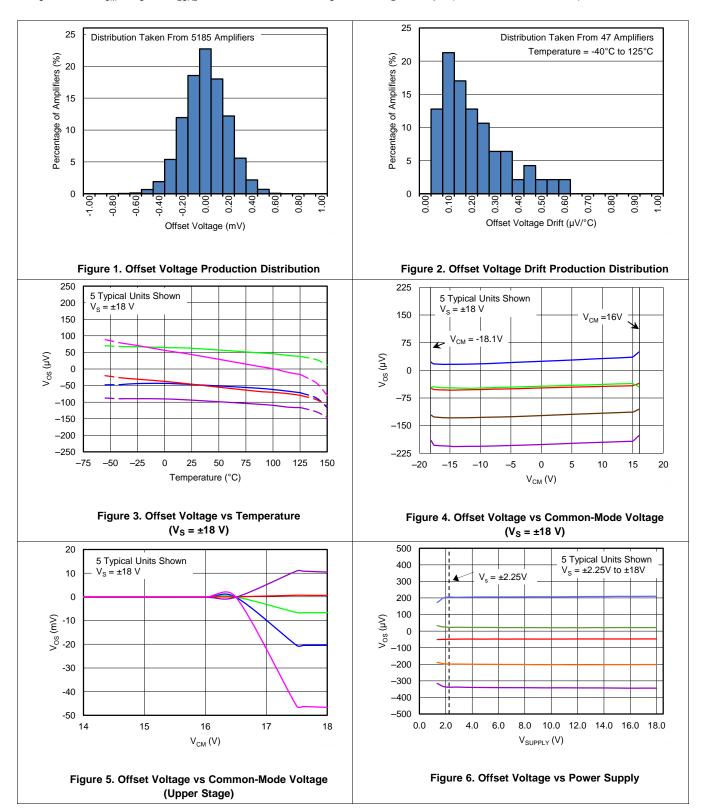
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# 7.6 Typical Characteristics

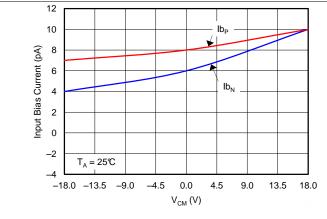
at  $V_S$  = ±18 V,  $V_{CM}$  =  $V_S$  / 2,  $R_{LOAD}$  = 10 k $\Omega$  connected to  $V_S$  / 2, and  $C_L$  = 100 pF (unless otherwise noted)



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# **Typical Characteristics (continued)**

at  $V_S = \pm 18$  V,  $V_{CM} = V_S / 2$ ,  $R_{LOAD} = 10$  k $\Omega$  connected to  $V_S / 2$ , and  $C_L = 100$  pF (unless otherwise noted)



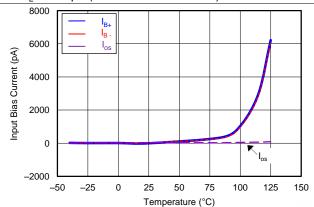
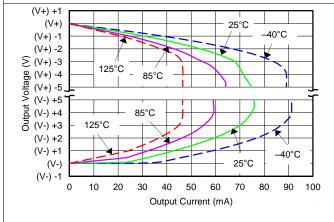


Figure 7. Input Bias Current vs Common-Mode Voltage

Figure 8. Input Bias Current vs Temperature



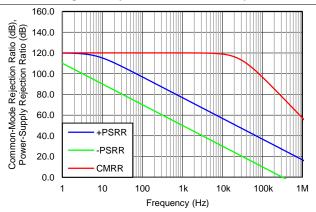
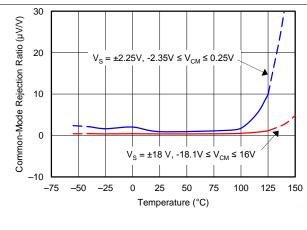


Figure 9. Output Voltage Swing vs Output Current (Maximum Supply)

Figure 10. CMRR and PSRR vs Frequency (Referred-to-Input)



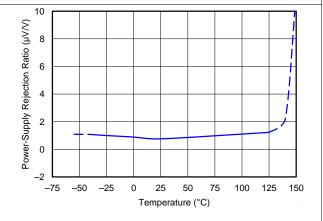
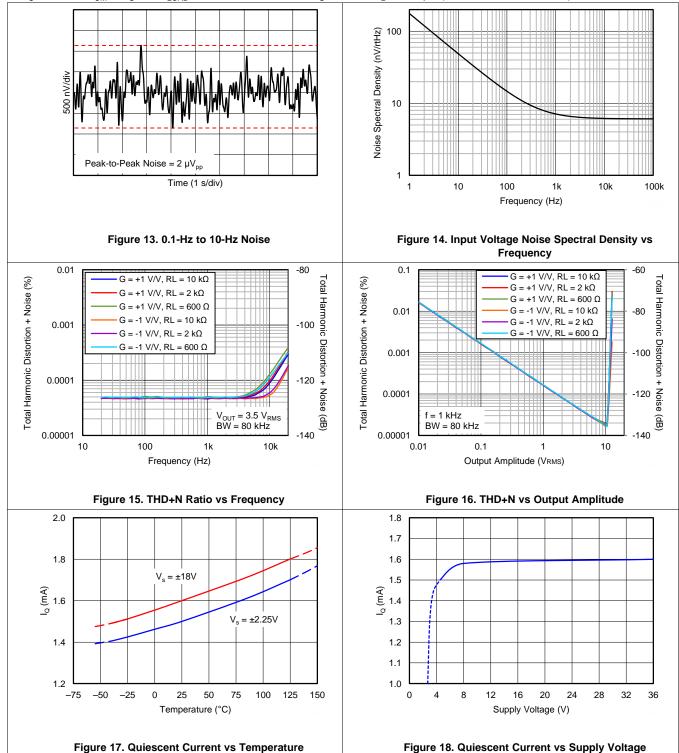


Figure 11. CMRR vs Temperature

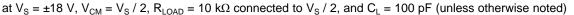
Figure 12. PSRR vs Temperature

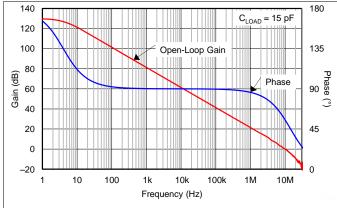


at  $V_S = \pm 18$  V,  $V_{CM} = V_S / 2$ ,  $R_{LOAD} = 10$  k $\Omega$  connected to  $V_S / 2$ , and  $C_L = 100$  pF (unless otherwise noted)









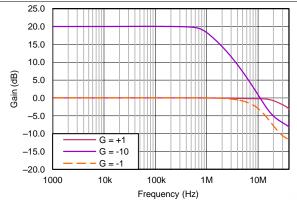
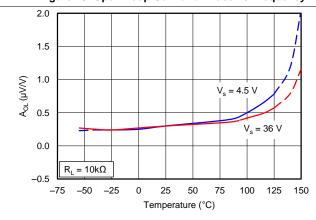


Figure 19. Open-Loop Gain and Phase vs Frequency

Figure 20. Closed-Loop Gain vs Frequency



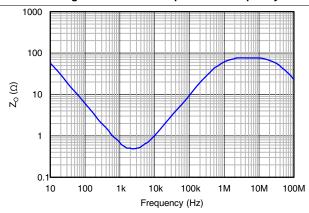
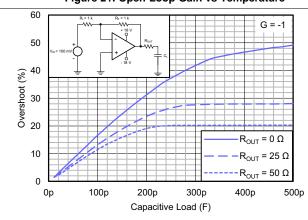


Figure 21. Open-Loop Gain vs Temperature

Figure 22. Open-Loop Output Impedance vs Frequency



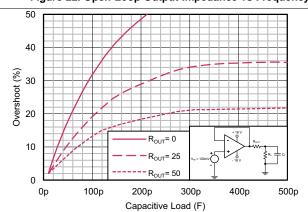


Figure 23. Small-Signal Overshoot vs Capacitive Load (100-mV Output Step)

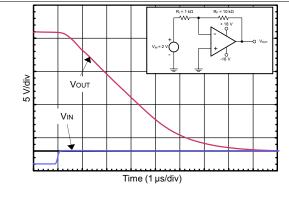
Figure 24. Small-Signal Overshoot vs Capacitive Load (100-mV Output Step)

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at  $V_S$  = ±18 V,  $V_{CM}$  =  $V_S$  / 2,  $R_{LOAD}$  = 10 k $\Omega$  connected to  $V_S$  / 2, and  $C_L$  = 100 pF (unless otherwise noted)



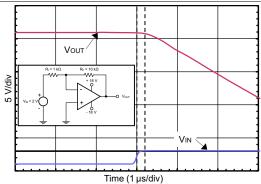
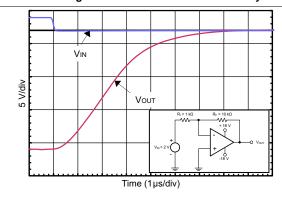


Figure 25. Positive Overload Recovery

Figure 26. Positive Overload Recovery (Zoomed In)



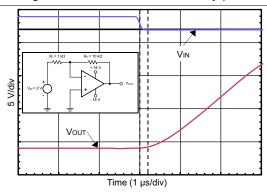
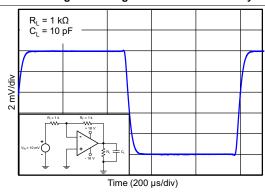


Figure 27. Negative Overload Recovery

Figure 28. Negative Overload Recovery (Zoomed In)



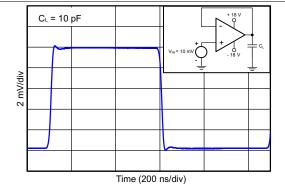


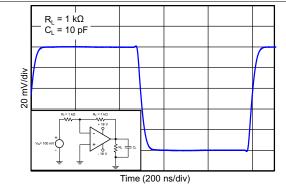
Figure 29. Small-Signal Step Response (10 mV, G = -1)

Figure 30. Small-Signal Step Response (10 mV, G = 1)

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at  $V_S$  = ±18 V,  $V_{CM}$  =  $V_S$  / 2,  $R_{LOAD}$  = 10 k $\Omega$  connected to  $V_S$  / 2, and  $C_L$  = 100 pF (unless otherwise noted)



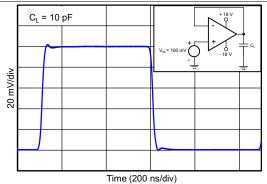
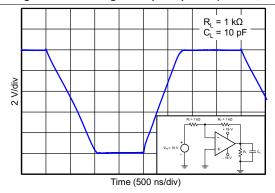


Figure 31. Small-Signal Step Response (100 mV, G = −1)

Figure 32. Small-Signal Step Response (100 mV, G = 1)



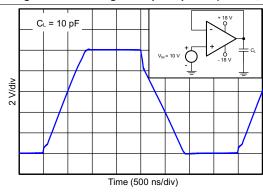
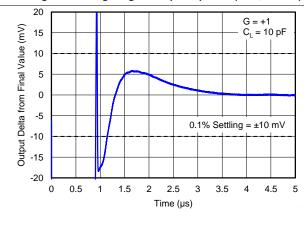


Figure 33. Large-Signal Step Response (10 V, G = −1)

Figure 34. Large-Signal Step Response (10 V, G = 1)



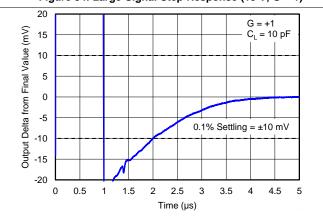
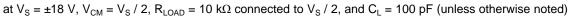


Figure 35. Large-Signal Settling Time (10-V Positive Step)

Figure 36. Large-Signal Settling Time (10-V Negative Step)





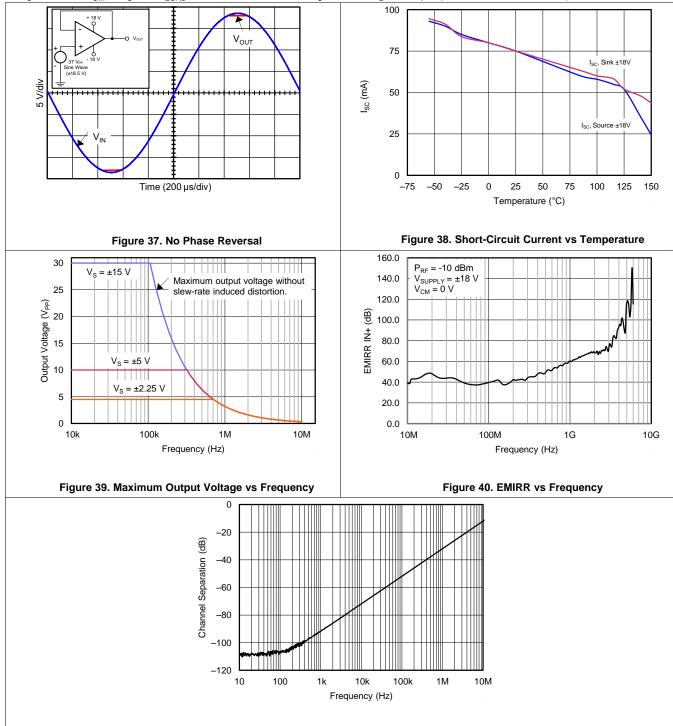


Figure 41. Channel Separation vs Frequency



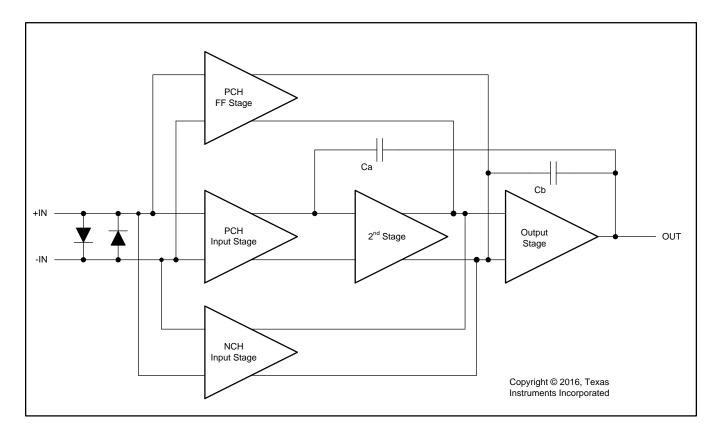
# 8 Detailed Description

#### 8.1 Overview

The OPAx172-Q1 family of operational amplifiers provide high overall performance, making the devices ideal for many general-purpose applications. The excellent offset drift of only 1.5  $\mu$ V/°C (maximum) provides excellent stability over the entire temperature range. In addition, the family offers very good overall performance with high CMRR, PSRR,  $A_{OI}$ , and superior THD.

The *Functional Block Diagram* section shows the simplified diagram of the OPA172-Q1 design. The design topology is a highly-optimized, three-stage amplifier with an active-feedforward gain stage.

# 8.2 Functional Block Diagram



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# 8.3 Feature Description

## 8.3.1 EMI Rejection

The OPAx172-Q1 uses integrated electromagnetic interference (EMI) filtering to reduce the effects of EMI from sources such as wireless communications and densely-populated boards with a mix of analog signal chain and digital components. EMI immunity can be improved with circuit design techniques; the OPAx172-Q1 benefits from these design improvements. Texas Instruments has developed the ability to accurately measure and quantify the immunity of an operational amplifier over a broad frequency spectrum extending from 10 MHz to 6 GHz. Figure 42 shows the results of this testing on the OPAx172-Q1. Table 3 shows the EMIRR IN+ values for the OPAx172-Q1 at particular frequencies commonly encountered in real-world applications. Applications listed in Table 3 can be centered on or operated near the particular frequency shown. Detailed information can also be found in the *EMI Rejection Ratio of Operational Amplifiers* application report (SBOA128), available for download from www.ti.com.

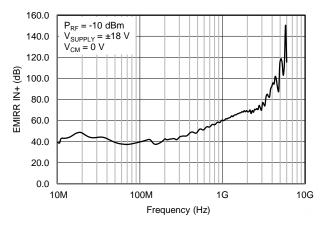


Figure 42. EMIRR Testing

Table 3. OPAx172-Q1 EMIRR IN+ for Frequencies of Interest

| FREQUENCY | APPLICATION OR ALLOCATION  | EMIRR IN+ |  |  |  |  |
|-----------|--|-----------|--|--|--|--|
| 400 MHz   | Mobile radio, mobile satellite, space operation, weather, radar, ultrahigh frequency (UHF) applications  |           |  |  |  |  |
| 900 MHz   | Global system for mobile communications (GSM) applications, radio communication, navigation, GPS (to 1.6 GHz), GSM, aeronautical mobile, UHF applications                        | 58.5 dB   |  |  |  |  |
| 1.8 GHz   | GSM applications, mobile personal communications, broadband, satellite, L-band (1 GHz to 2 GHz)  | 68 dB     |  |  |  |  |
| 2.4 GHz   | 802.11b, 802.11g, 802.11n, Bluetooth®, mobile personal communications, industrial, scientific and medical (ISM) radio band, amateur radio and satellite, S-band (2 GHz to 4 GHz) | 69.2 dB   |  |  |  |  |
| 3.6 GHz   | Radiolocation, aero communication and navigation, satellite, mobile, S-band  | 82.9 dB   |  |  |  |  |
| 5 GHz     | 802.11a, 802.11n, aero communication and navigation, mobile communication, space and satellite operation, C-band (4 GHz to 8 GHz)  | 114 dB    |  |  |  |  |



#### 8.3.2 Phase-Reversal Protection

The OPAx172-Q1 family has internal phase-reversal protection. Many op amps exhibit a phase reversal when the input is driven beyond the linear common-mode range. This condition is most often encountered in noninverting circuits when the input is driven beyond the specified common-mode voltage range, causing the output to reverse into the opposite rail. The input of the OPAx172-Q1 prevents phase reversal with excessive common-mode voltage. Instead, the appropriate rail limits the output voltage. This performance is shown in Figure 43.

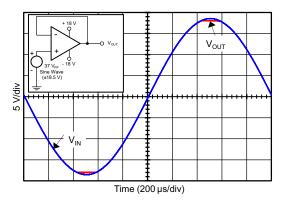


Figure 43. No Phase Reversal

#### 8.3.3 Capacitive Load and Stability

The dynamic characteristics of the OPAx172-Q1 are optimized for commonly-used operating conditions. The combination of low closed-loop gain and high capacitive loads decreases the phase margin of the amplifier and can lead to gain peaking or oscillations. As a result, heavier capacitive loads must be isolated from the output. The simplest way to achieve this isolation is to add a small resistor (for example,  $R_{OUT} = 50~\Omega$ ) in series with the output. Figure 44 and Figure 45 show graphs of small-signal overshoot versus capacitive load for several values of  $R_{OUT}$ . See the *Feedback Plots Define Op Amp AC Performance* application bulletin (SBOA015), available for download from www.ti.com, for details of analysis techniques and application circuits.

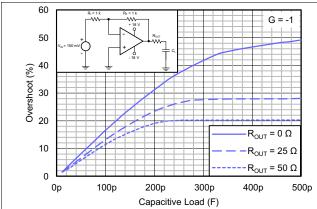


Figure 44. Small-Signal Overshoot vs Capacitive Load (100-mV Output Step)

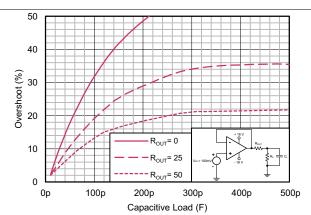


Figure 45. Small-Signal Overshoot vs Capacitive Load (100-mV Output Step)

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#### 8.4 Device Functional Modes

# 8.4.1 Common-Mode Voltage Range

The input common-mode voltage range of the OPAx172-Q1 series extends 100 mV below the negative rail and within 2 V of the top rail for normal operation.

This device can operate with a full rail-to-rail input 100 mV beyond the top rail, but with reduced performance within 2 V of the top rail. The typical performance in this range is summarized in Table 4.

Table 4. Typical Performance Range ( $V_S = \pm 18 \text{ V}$ )

|  | MIN      | TYP | MAX        | UNIT               |
|--|----------|-----|------------|--------------------|
| Input common-mode voltage  | (V+) - 2 |     | (V+) + 0.1 | V                  |
| Offset voltage   |          | 5   |            | mV                 |
| Offset voltage vs temperature (T <sub>A</sub> = -40°C to +125°C) |          | 10  |            | μV/°C              |
| Common-mode rejection  |          | 70  |            | dB                 |
| Open-loop gain   |          | 60  |            | dB                 |
| Gain bandwidth product (GBP)                                     |          | 4   |            | MHz                |
| Slew rate  |          | 4   |            | V/µs               |
| Noise at f = 1 kHz   |          | 22  |            | nV/√ <del>Hz</del> |

#### 8.4.2 Electrical Overstress

Designers often ask questions about the capability of an operational amplifier to withstand electrical overstress. These questions tend to focus on the device inputs, but can involve the supply voltage terminals or even the output terminal. Each of these different terminal functions have electrical stress limits determined by the voltage breakdown characteristics of the particular semiconductor fabrication process and specific circuits connected to the terminal. Additionally, internal electrostatic discharge (ESD) protection is built into these circuits for protection from accidental ESD events both before and during product assembly.

A good understanding of this basic ESD circuitry and the relevance to an electrical overstress event is helpful. Figure 46 illustrates the ESD circuits contained in the OPAx172-Q1 (indicated by the dashed line area). The ESD protection circuitry involves several current-steering diodes connected from the input and output terminals and routed back to the internal power-supply lines, where the diodes meet at an absorption device internal to the operational amplifier. This protection circuitry is intended to remain inactive during normal circuit operation.



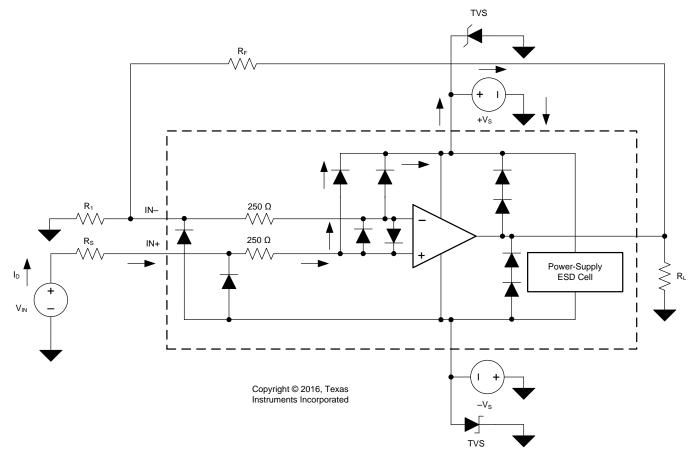


Figure 46. Equivalent Internal ESD Circuitry Relative to a Typical Circuit Application

An ESD event produces a short-duration, high-voltage pulse that is transformed into a short-duration, high-current pulse when discharging through a semiconductor device. The ESD protection circuits are designed to provide a current path around the operational amplifier core to prevent damage. The energy absorbed by the protection circuitry is then dissipated as heat.

When an ESD voltage develops across two or more amplifier device terminals, current flows through one or more steering diodes. Depending on the path that the current takes, the absorption device can activate. The absorption device has a trigger, or threshold voltage, that is above the normal operating voltage of the OPAx172-Q1 but below the device breakdown voltage level. When this threshold is exceeded, the absorption device quickly activates and clamps the voltage across the supply rails to a safe level.

When the operational amplifier connects into a circuit (as shown in Figure 46), the ESD protection components are intended to remain inactive and do not become involved in the application circuit operation. However, circumstances can arise where an applied voltage exceeds the operating voltage range of a given terminal. If this condition occurs, there is a risk that some internal ESD protection circuits can turn on and conduct current. Any such current flow occurs through steering-diode paths and rarely involves the absorption device.

Figure 46 shows a specific example where the input voltage  $(V_{IN})$  exceeds the positive supply voltage  $(+V_S)$  by 500 mV or more. Much of what happens in the circuit depends on the supply characteristics. If  $+V_S$  can sink the current, one of the upper input steering diodes conducts and directs current to  $+V_S$ . Excessively high current levels can flow with increasingly higher  $V_{IN}$ . As a result, the data sheet specifications recommend that applications limit the input current to 10 mA.

If the supply is not capable of sinking the current,  $V_{IN}$  can begin sourcing current to the operational amplifier, and then take over as the source of positive supply voltage. The danger in this case is that the voltage can rise to levels that exceed the operational amplifier absolute maximum ratings.

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Another common question involves what happens to the amplifier if an input signal is applied to the input when the power supplies  $+V_S$  or  $-V_S$  are at 0 V. Again, this question depends on the supply characteristic when at 0 V, or at a level below the input-signal amplitude. If the supplies appear as high impedance, then the input source supplies the operational amplifier current through the current-steering diodes. This state is not a normal bias condition; most likely, the amplifier does not operate normally. If the supplies are low impedance, then the current through the steering diodes can become quite high. The current level depends on the ability of the input source to deliver current, and any resistance in the input path.

If there is any uncertainty about the ability of the supply to absorb this current, add external zener diodes to the supply terminals; see Figure 46. Select the zener voltage so that the diode does not turn on during normal operation. However, the zener voltage must be low enough so that the zener diode conducts if the supply terminal begins to rise above the safe-operating, supply-voltage level.

The OPAx172-Q1 input terminals are protected from excessive differential voltage with back-to-back diodes; see Figure 46. In most circuit applications, the input protection circuitry has no effect. However, in low-gain or G=1 circuits, fast-ramping input signals can forward-bias these diodes because the output of the amplifier cannot respond rapidly enough to the input ramp. If the input signal is fast enough to create this forward-bias condition, limit the input signal current to 10 mA or less. If the input signal current is not inherently limited, an input series resistor can be used to limit the input signal current. This input series resistor degrades the low-noise performance of the OPAx172-Q1. Figure 46 illustrates an example configuration that implements a current-limiting feedback resistor.

#### 8.4.3 Overload Recovery

Overload recovery is defined as the time required for the op amp output to recover from the saturated state to the linear state. The output devices of the op amp enter the saturation region when the output voltage exceeds the rated operating voltage, either resulting from the high input voltage or the high gain. After the device enters the saturation region, the charge carriers in the output devices need time to return back to the normal state. After the charge carriers return back to the equilibrium state, the device begins to slew at the normal slew rate. Thus, the propagation delay in case of an overload condition is the sum of the overload recovery time and the slew time. The overload recovery time for the OPAx172-Q1 is approximately 200 ns.



# 9 Applications and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

# 9.1 Application Information

The OPAx172-Q1 family of amplifiers is specified for operation from 4.5 V to 36 V (±2.25 V to ±18 V). Many of the specifications apply from –40°C to +125°C. Parameters that can exhibit significant variance with regard to operating voltage or temperature are presented in the *Typical Characteristics* section.

## 9.2 Typical Applications

The following application examples highlight only a few of the circuits where the OPAx172-Q1 can be used.

#### 9.2.1 Capacitive Load Drive Solution Using an Isolation Resistor

The OPA172-Q1 can be used capacitive loads such as cable shields, reference buffers, MOSFET gates, and diodes. The circuit uses an isolation resistor ( $R_{\rm ISO}$ ) to stabilize the output of an op amp.  $R_{\rm ISO}$  modifies the open-loop gain of the system to ensure the circuit has sufficient phase margin, as shown in Figure 47.

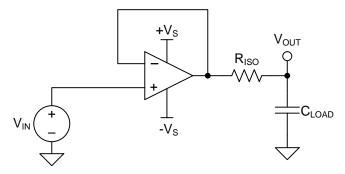


Figure 47. Unity-Gain Buffer with R<sub>ISO</sub> Stability Compensation

#### 9.2.1.1 Design Requirements

The design requirements are:

Supply voltage: 30 V (±15 V)

Capacitive loads: 100 pF, 1000 pF, 0.01 μF, 0.1 μF, and 1 μF

Phase margin: 45° and 60°

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# **Typical Applications (continued)**

#### 9.2.1.2 Detailed Design Procedure

Figure 47 depicts a unity-gain buffer driving a capacitive load. Equation 1 shows the transfer function for the circuit in Figure 47. Not depicted in Figure 47 is the open-loop output resistance of the op amp, Ro.

$$T(s) = \frac{1 + C_{LOAD} \times R_{ISO} \times s}{1 + (R_o + R_{ISO}) \times C_{LOAD} \times s}$$
(1)

The transfer function in Equation 1 has a pole and a zero. The frequency of the pole ( $f_0$ ) is determined by ( $R_0$  +  $R_{ISO}$ ) and  $C_{LOAD}$ . Components  $R_{ISO}$  and  $C_{LOAD}$  determine the frequency of the zero (f<sub>z</sub>). A stable system is obtained by selecting  $R_{ISO}$  such that the rate of closure (ROC) between the open-loop gain (A<sub>OL</sub>) and 1 /  $\beta$  is 20 dB per decade. Figure 48 shows the concept. Note that the 1 / β curve for a unity-gain buffer is 0 dB.

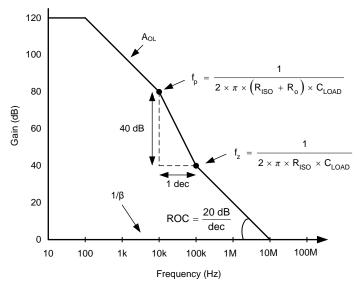


Figure 48. Unity-Gain Amplifier with R<sub>ISO</sub> Compensation

ROC stability analysis is typically simulated. The validity of the analysis depends on multiple factors, especially the accurate modeling of R<sub>o</sub>. In addition to simulating the ROC, a robust stability analysis includes a measurement of overshoot percentage and ac gain peaking of the circuit using a function generator, oscilloscope, and gain and phase analyzer. Phase margin is then calculated from these measurements. Table 5 shows the overshoot percentage and ac gain peaking that correspond to phase margins of 45° and 60°. For more details on this design and other alternative devices that can be used in place of the OPA172-Q1, see the Capacitive Load Drive Solution using an Isolation Resistorprecision design (TIPD128).

Table 5. Phase Margin versus Overshoot and AC Gain Peaking

| PHASE MARGIN | OVERSHOOT | AC GAIN PEAKING |  |  |  |
|--------------|-----------|-----------------|--|--|--|
| 45°          | 23.3%     | 2.35 dB         |  |  |  |
| 60°          | 8.8%      | 0.28 dB         |  |  |  |

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#### 9.2.1.3 Application Curve

The OPA172-Q1 meets the supply voltage requirements of 30 V. The OPA172-Q1 is tested for various capacitive loads and R<sub>ISO</sub> is adjusted to get an overshoot corresponding to Table 5. The results of the these tests are summarized in Figure 49.

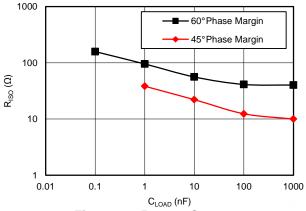


Figure 49. R<sub>ISO</sub> vs C<sub>LOAD</sub>

#### 9.2.2 Bidirectional Current Source

The improved Howland current-pump topology shown in Figure 50 provides excellent performance because of the extremely tight tolerances of the on-chip resistors of the INA132. By buffering the output using an OPA172-Q1, the output current the circuit is able to deliver is greatly extended.

The circuit dc transfer function is shown in Equation 2.

$$I_{OUT} = V_{IN} / R1 \tag{2}$$

The OPA172-Q1 can also be used as the feedback amplifier because the low bias current minimizes error voltages produced across R1. However, for improved performance, select a FET-input device with extremely low offset, such as the OPA192, OPA140, or OPA188 as the feedback amplifier.

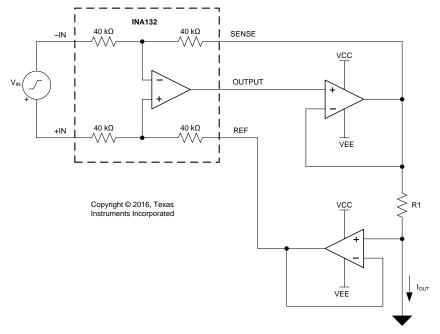


Figure 50. Bidirectional Current Source

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#### 9.2.3 JFET-Input Low-Noise Amplifier

Figure 51 shows a low-noise composite amplifier built by adding a low noise JFET pair (Q1 and Q2) as an input preamplifier for the OPA172-Q1. Transistors Q3 and Q4 form a 2-mA current sink that biases each JFET with 1 mA of drain current. Using  $3.9-k\Omega$  drain resistors produces a gain of approximately 10 in the input amplifier, making the extremely-low, broadband-noise spectral density of the JFET pair, Q1 and Q2, the dominant noise source of the amplifier. The output impedance of the input differential amplifier is large enough that a FET-input amplifier such as the OPA172-Q1 provides superior noise performance over bipolar-input amplifiers.

The gain of the composite amplifier is given by Equation 3.

$$A_V = (1 + R3 / R4)$$
 (3)

The resistances shown are standard 1% resistor values that produce a gain of approximately 100 (99.26) with 68° of phase margin. Gains less than 10 may require additional compensation methods to provide stability. Select low resistor values to minimize the resistor thermal noise contribution to the total output noise.

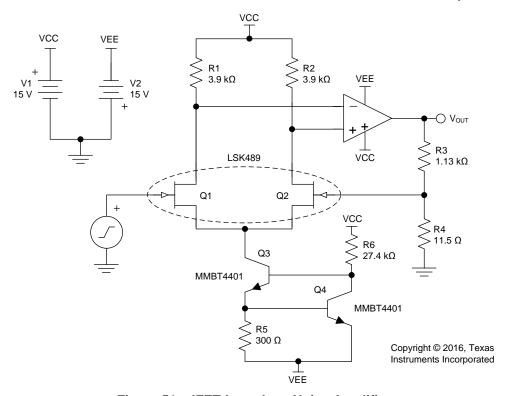


Figure 51. JFET-Input Low-Noise Amplifier



# 10 Power Supply Recommendations

The OPA172-Q1 is specified for operation from 4.5 V to 36 V (±2.25 V to ±18 V); many specifications apply from -40°C to +125°C. Parameters that can exhibit significant variance with regard to operating voltage or temperature are presented in the *Typical Characteristics* section.

#### CAUTION

Supply voltages larger than 40 V can permanently damage the device; see the Absolute Maximum Ratings table.

Place 0.1-μF bypass capacitors close to the power-supply terminals to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, see the Layout section.

# 11 Layout

## 11.1 Layout Guidelines

For best operational performance of the device, use good printed circuit board (PCB) layout practices, including:

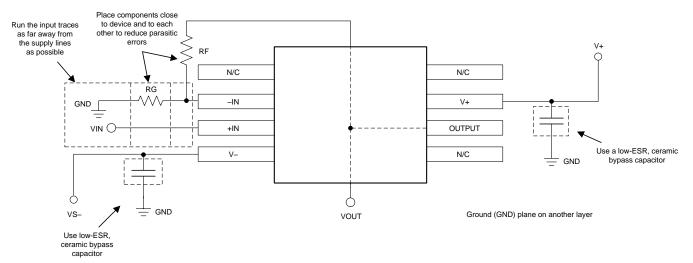
- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and of op amp itself. Bypass capacitors are used to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
  - Connect low-ESR, 0.1-µF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for singlesupply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically separate digital and analog grounds paying attention to the flow of the ground current.
- In order to reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If these traces cannot be kept separate, crossing the sensitive trace perpendicular as opposed to in parallel with the noisy trace is preferable.
- Place the external components as close to the device as possible. As illustrated in Figure 52, keeping RF and RG close to the inverting input minimizes parasitic capacitance.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.

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# 11.2 Layout Example



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Figure 52. Operational Amplifier Board Layout for a Noninverting Configuration



# 12 Device and Documentation Support

#### 12.1 Device Support

#### 12.1.1 Development Support

#### 12.1.1.1 TINA-TI™ (Free Software Download)

TINA-TI<sup>TM</sup> is a simple, powerful, and easy-to-use circuit simulation program based on a SPICE engine. TINA-TI<sup>TM</sup> is a free, fully-functional version of the TINA-TI<sup>TM</sup> software, preloaded with a library of macro models in addition to a range of both passive and active models. TINA-TI<sup>TM</sup> provides all the conventional dc, transient, and frequency domain analysis of SPICE, as well as additional design capabilities.

Available as a free download from the Analog eLab Design Center, TINA-TI<sup>TM</sup> offers extensive post-processing capability that allows users to format results in a variety of ways. Virtual instruments offer the ability to select input waveforms and probe circuit nodes, voltages, and waveforms, creating a dynamic guick-start tool.

#### NOTE

These files require that either the TINA software (from DesignSoft™) or TINA-TI™ software be installed. Download the free TINA-TI™ software from the TINA-TI™ folder.

## 12.2 Documentation Support

#### 12.2.1 Related Documentation

For related documentation see the following:

- Feedback Plots Define Op Amp AC Performance (SBOA015)
- EMI Rejection Ratio of Operational Amplifiers (SBOA128)
- Capacitive Load Drive Solution using an Isolation Resistor (TIDU032)
- INA132 Low Power, Single-Supply Difference Amplifier (SBOS059)
- OPAx192 36-V, Precision, Rail-to-Rail Input/Output, Low Offset Voltage, Low Input Bias Current Op Amp with e-trim™ (SBOS620)
- OPA140 High-Precision, Low-Noise, Rail-to-Rail Output, 11-MHz JFET Op Amp (SBOS498)
- OPA188 Precision, Low-Noise, Rail-to-Rail Output, 36-V, Zero-Drift Operational Amplifier (SBOS642)

#### 12.3 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to order now.

Table 6. Related Links

| PARTS      | PRODUCT FOLDER | RODUCT FOLDER ORDER NOW |            | TOOLS & SOFTWARE | SUPPORT & COMMUNITY |  |
|------------|----------------|-------------------------|------------|------------------|---------------------|--|
| OPA2172-Q1 | Click here     | Click here              | Click here | Click here       | Click here          |  |
| OPA4172-Q1 | Click here     | Click here              | Click here | Click here       | Click here          |  |

# 12.4 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.



## 12.5 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 12.6 Trademarks

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Bluetooth is a registered trademark of Bluetooth SIG, Inc.
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All other trademarks are the property of their respective owners.

#### 12.7 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 12.8 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

# 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

www.ti.com 7-Oct-2025

#### PACKAGING INFORMATION

| Orderable part number | Status | Material type | Package   Pins  | Package qty   Carrier | RoHS | Lead finish/  | MSL rating/         | Op temp (°C) | Part marking |
|-----------------------|--------|---------------|-----------------|-----------------------|------|---------------|---------------------|--------------|--------------|
|                       | (1)    | (2)           |                 |                       | (3)  | Ball material | Peak reflow         |              | (6)          |
|                       |        |               |                 |                       |      | (4)           | (5)                 |              |              |
| OPA2172QDGKQ1         | Active | Production    | VSSOP (DGK)   8 | 80   TUBE             | Yes  | NIPDAUAG      | Level-2-260C-1 YEAR | -40 to 125   | 18W6         |
| OPA2172QDGKQ1.B       | Active | Production    | VSSOP (DGK)   8 | 80   TUBE             | Yes  | NIPDAUAG      | Level-2-260C-1 YEAR | -40 to 125   | 18W6         |
| OPA2172QDGKRQ1        | Active | Production    | VSSOP (DGK)   8 | 2500   LARGE T&R      | Yes  | NIPDAUAG      | Level-2-260C-1 YEAR | -40 to 125   | 18W6         |
| OPA2172QDGKRQ1.B      | Active | Production    | VSSOP (DGK)   8 | 2500   LARGE T&R      | Yes  | NIPDAUAG      | Level-2-260C-1 YEAR | -40 to 125   | 18W6         |
| OPA4172AQPWRQ1        | Active | Production    | TSSOP (PW)   14 | 2000   LARGE T&R      | Yes  | NIPDAU        | Level-2-260C-1 YEAR | -40 to 125   | 4172Q1       |
| OPA4172AQPWRQ1.B      | Active | Production    | TSSOP (PW)   14 | 2000   LARGE T&R      | Yes  | NIPDAU        | Level-2-260C-1 YEAR | -40 to 125   | 4172Q1       |

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

# PACKAGE OPTION ADDENDUM

www.ti.com 7-Oct-2025

#### OTHER QUALIFIED VERSIONS OF OPA2172-Q1, OPA4172-Q1:

● Catalog : OPA2172, OPA4172

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 24-Jul-2025

# TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width     |
|----|---|
| В0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

| Device         | Package<br>Type | Package<br>Drawing |    | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|----------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| OPA2172QDGKRQ1 | VSSOP           | DGK                | 8  | 2500 | 330.0                    | 12.4                     | 5.3        | 3.4        | 1.4        | 8.0        | 12.0      | Q1               |
| OPA4172AQPWRQ1 | TSSOP           | PW                 | 14 | 2000 | 330.0                    | 12.4                     | 6.9        | 5.6        | 1.6        | 8.0        | 12.0      | Q1               |

www.ti.com 24-Jul-2025



## \*All dimensions are nominal

| Device         | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| OPA2172QDGKRQ1 | VSSOP        | DGK             | 8    | 2500 | 366.0       | 364.0      | 50.0        |
| OPA4172AQPWRQ1 | TSSOP        | PW              | 14   | 2000 | 353.0       | 353.0      | 32.0        |

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 24-Jul-2025

# **TUBE**



#### \*All dimensions are nominal

| Device          | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (µm) | B (mm) |
|-----------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| OPA2172QDGKQ1   | DGK          | VSSOP        | 8    | 80  | 330    | 6.55   | 500    | 2.88   |
| OPA2172QDGKQ1.B | DGK          | VSSOP        | 8    | 80  | 330    | 6.55   | 500    | 2.88   |





#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







#### NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.





NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.





NOTES: (continued)

- 11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 12. Board assembly site may have different recommendations for stencil design.



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